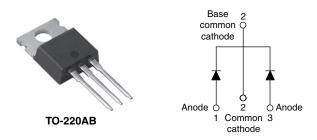
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Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY						
Package	TO-220AB					
I _{F(AV)}	2 x 20 A					
V _R	15 V					
V _F at I _F	See Electrical table					
I _{RM} max.	600 mA at 100 °C					
T _J max.	125 °C					
Diode variation	Common cathode					
E _{AS}	10 mJ					

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 COMPLIANT HALOGEN
- Guard ring for enhanced ruggedness and long FREE
 Available
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	40	A					
V _{RRM}		15	V					
I _{FSM}	t _p = 5 μs sine	700	А					
V _F	19 A _{pk} , T _J = 125 °C (per leg)	0.25	V					
TJ	Range	- 55 to 125	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-40L15CTPbF	VS-40L15CT-N3	UNITS				
Maximum DC reverse voltage	V _R	15	15	V				
Maximum working peak reverse voltage	V _{RWM}	15	15	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average forward current	per leg	Iran	50 % duty cycle at $T_{\rm C}$ = 85 °C, rectangular waveform		20				
See fig. 5	per device	I _{F(AV)}	30 /0 duty cycle at $1^{\circ}_{\circ} = 00^{\circ}_{\circ}$ 0, 1	40	•				
	Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse Following any rated		700	A			
surge current per leg See fig. 7		IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	330				
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH		10	mJ			
Repetitive avalanche curre	ent per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CON	DITIONS	TYP.	MAX.	UNITS	
		19 A	T.I = 25 °C	-	0.41	V	
Forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1)=25 0	-	0.52		
See fig. 1	VFM ("	19 A	T.I = 125 °C	0.25	0.33		
		40 A	$1_{j} = 125$ C	0.37	0.50		
Reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA	
See fig. 2		T _J = 100 °C	V _R = naleu V _R	-	600		
Threshold voltage	V _{F(TO)}	V _{F(TO)} 0.182		182	V		
Forward slope resistance	r _t	$I_{\rm J} = I_{\rm J}$ maximum	$T_J = T_J$ maximum		.6	mΩ	
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	2000	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm	8	-	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs	

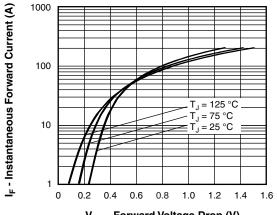
Note

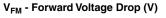
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

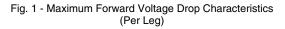
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 125	°C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0/11		
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torque minimum			6 (5)	kgf ⋅ cm		
maximum			12 (10)	(lbf ⋅ in)		
Marking device		Case style TO-220AB	40L1	5CT		



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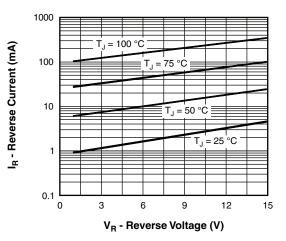


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

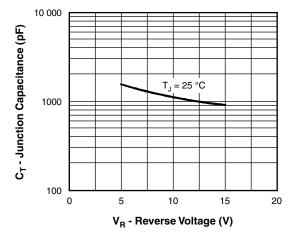
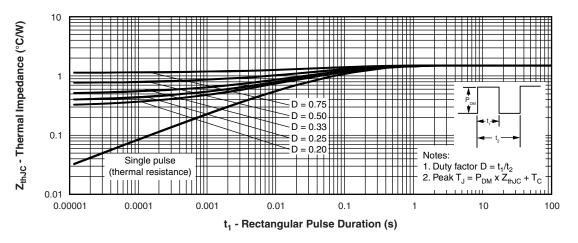


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

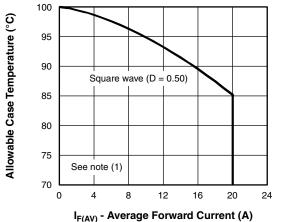


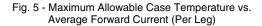


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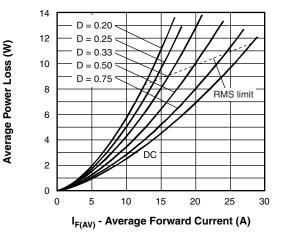


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

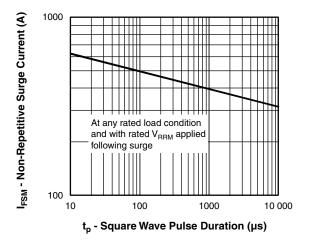


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

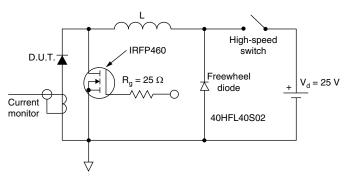


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

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ORDERING INFORMATION TABLE

Device code	vs-	40	L	15	С	т	PbF
		2	(3)	4	(5)	6	(7)
	1 - 2 - 3 - 4 - 5 - 6 -	Cur Sch Volt C = Pac T =	rent ratii ottky "L' age rati Commo kage: TO-220	ng (40 = ' series ng (15 = on catho	: 15 V) de	duct	-
	7 -			ntal digit ad (Pb)	-free and	d RoHS	compli
		• -	N3 = Ha	logen-fr	ee, RoH	S comp	oliant, a

ORDERING INFO	ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40L15CTPbF	50	1000	Antistatic plastic tube					
VS-40L15CT-N3	50	1000	Antistatic plastic tube					

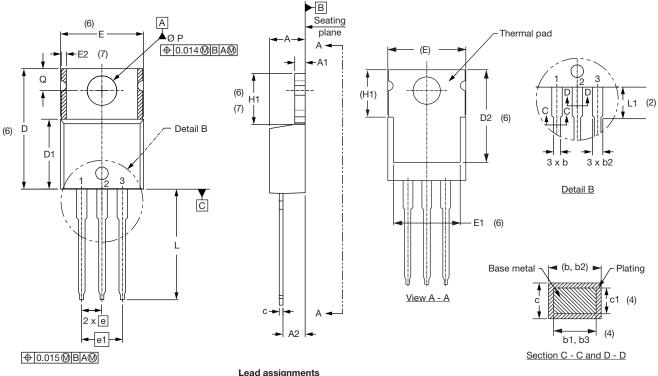
LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95222						
Port marking information	TO-220AB PbF	www.vishay.com/doc?95225				
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028				

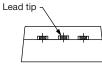


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TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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